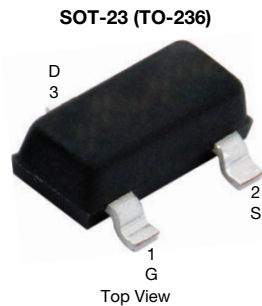


## P-Channel 30 V (D-S) MOSFET



Marking code: N7

PRODUCT SUMMARY	
$V_{DS}$ (V)	-30
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -10$ V	0.088
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -4.5$ V	0.138
$Q_g$ typ. (nC)	4.1
$I_D$ (A) <sup>a, b</sup>	-3.5
Configuration	Single

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free	Si2307CDS-T1-E3
Lead (Pb)-free and halogen-free	Si2307CDS-T1-GE3

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	$V_{DS}$	-30	V
Gate-source voltage	$V_{GS}$	$\pm 20$	
Continuous drain current ( $T_J = 150$ °C) <sup>a, b</sup>	$I_D$	$T_C = 25$ °C	-3.5
		$T_C = 70$ °C	-2.8
		$T_A = 25$ °C	-2.7 <sup>a, b</sup>
		$T_A = 70$ °C	-2.2 <sup>a, b</sup>
Pulsed drain current (10 $\mu$ s pulse width)	$I_{DM}$	-12	A
Continuous source-drain diode current <sup>a, b</sup>	$I_S$	$T_C = 25$ °C	
		$T_A = 25$ °C	-0.91 <sup>a, b</sup>
Maximum power dissipation <sup>a, b</sup>	$P_D$	$T_C = 25$ °C	1.8
		$T_C = 70$ °C	1.14
		$T_A = 25$ °C	1.1 <sup>a, b</sup>
		$T_A = 70$ °C	0.7 <sup>a, b</sup>
		Operating junction and storage temperature range	$T_J, T_{stg}$
Soldering recommendations (peak temperature) <sup>c</sup>		260	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient <sup>a, c</sup>	$t \leq 5$ s	$R_{thJA}$	90	115	°C/W
Maximum junction-to-foot (drain)	Steady state	$R_{thJF}$	55	70	

**Notes**

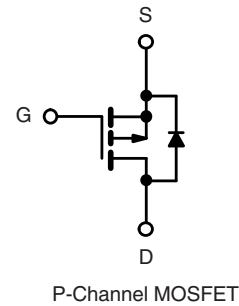
- Surface mounted on 1" x 1" FR4 board
- $t = 5$  s
- Maximum under steady state conditions is 166 °C/W

**FEATURES**

- TrenchFET® power MOSFET
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

**APPLICATIONS**

- Load switch for portable devices





SPECIFICATIONS $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
<b>Static</b>						
Drain-source breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-30	-	-	V
$V_{DS}$ temperature coefficient	$\Delta V_{DS}/T_J$	$I_D = -250\text{ }\mu\text{A}$	-	-32	-	mV/ $^\circ\text{C}$
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	4.5	-	
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-1	-	-3	V
Gate-source leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	-100	nA
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$	-	-	-1	$\mu\text{A}$
		$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$	-	-	-10	
On-state drain current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq 5\text{ V}, V_{GS} = -10\text{ V}$	-6	-	-	A
Drain-source on-state resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -10\text{ V}, I_D = -3.5\text{ A}$	-	0.073	0.088	$\Omega$
		$V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$	-	0.110	0.138	
Forward transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -10\text{ V}, I_D = -3.5\text{ A}$	-	7	-	S
<b>Dynamic <sup>b</sup></b>						
Input capacitance	$C_{iss}$	$V_{DS} = -15\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	-	340	-	pF
Output capacitance	$C_{oss}$		-	67	-	
Reverse transfer capacitance	$C_{rss}$		-	51	-	
Total gate charge	$Q_g$	$V_{DS} = -15\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$	-	4.1	6.2	nC
Gate-source charge	$Q_{gs}$		-	1.3	-	
Gate-drain charge	$Q_{gd}$		-	1.8	-	
Gate resistance	$R_g$	$f = 1\text{ MHz}$	-	10	-	$\Omega$
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, R_L = 15\text{ }\Omega$ $I_D \cong -1\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$	-	40	60	ns
Rise time	$t_r$		-	40	60	
Turn-off delay time	$t_{d(off)}$		-	20	40	
Fall time	$t_f$		-	17	30	
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, R_L = 15\text{ }\Omega$ $I_D \cong -1\text{ A}, V_{GEN} = -10\text{ V}, R_g = 1\text{ }\Omega$	-	5.5	10	
Rise time	$t_r$		-	13	25	
Turn-off delay time	$t_{d(off)}$		-	17	30	
Fall time	$t_f$		-	7.7	15	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous source-drain diode current	$I_S$	$T_C = 25\text{ }^\circ\text{C}$	-	-	-1.5	A
Pulse diode forward current	$I_{SM}$		-	-	-12	
Body diode voltage	$V_{SD}$	$I_S = -0.75\text{ A}, V_{GS} = 0\text{ V}$	-	-0.8	-1.2	V
Body diode reverse recovery time	$t_{rr}$	$I_F = -2.5\text{ A}, di/dt = 100\text{ A}/\mu\text{s},$ $T_J = 25\text{ }^\circ\text{C}$	-	17	30	ns
Body diode reverse recovery charge	$Q_{rr}$		-	11	20	nC
Reverse recovery fall time	$t_a$		-	12	-	ns
Reverse recovery rise time	$t_b$		-	5	-	

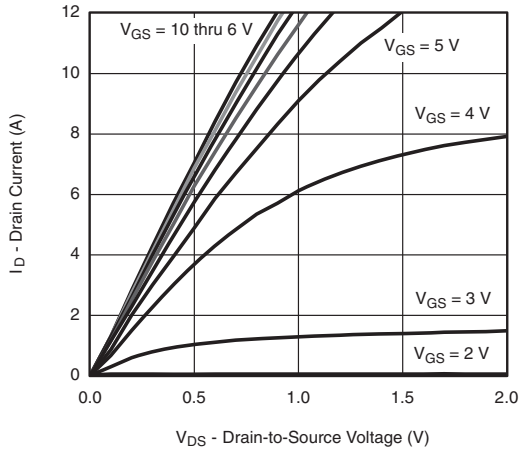
**Notes**

- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\text{ }\%$
- b. Guaranteed by design, not subject to production testing

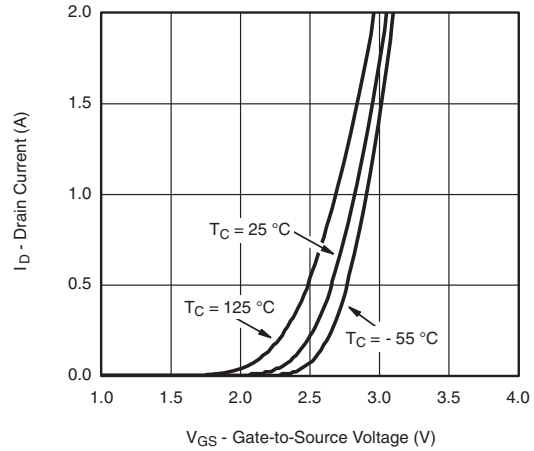
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



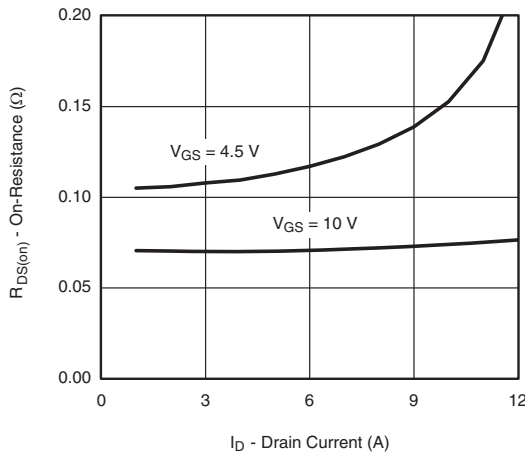
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



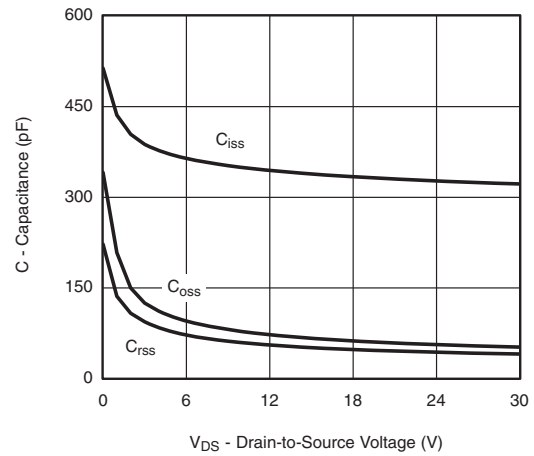
**Output Characteristics**



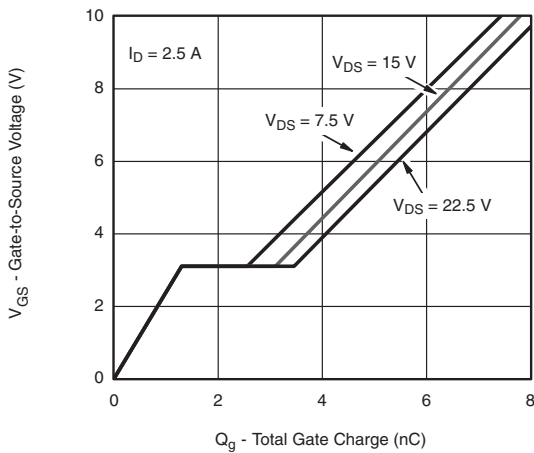
**Transfer Characteristics**



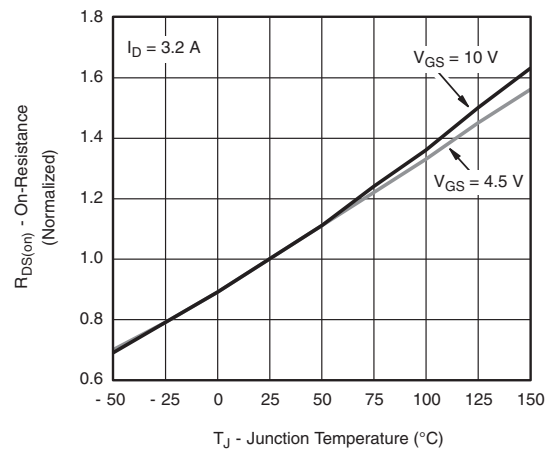
**On-Resistance vs. Drain Current and Gate Voltage**



**Capacitance**



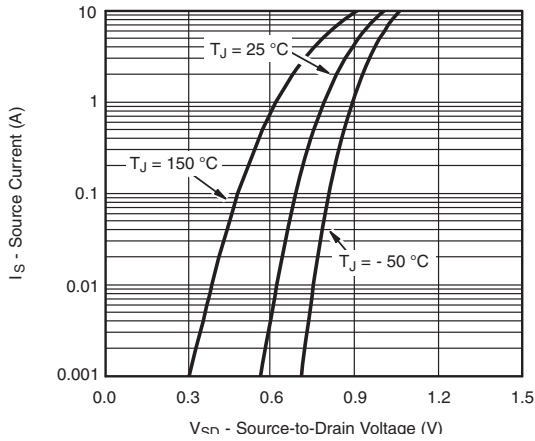
**Gate Charge**



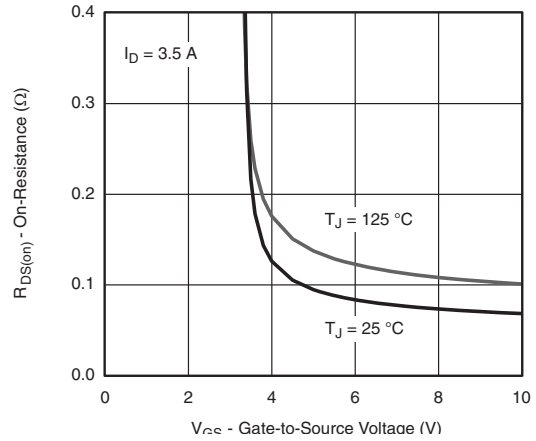
**On-Resistance vs. Junction Temperature**



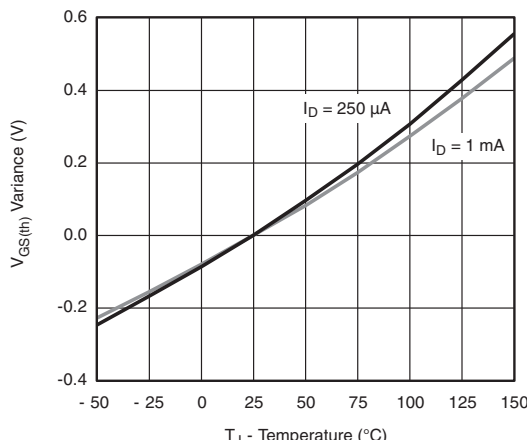
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



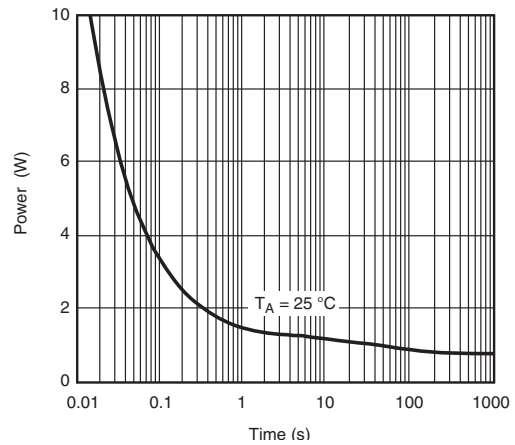
**Source-Drain Diode Forward Voltage**



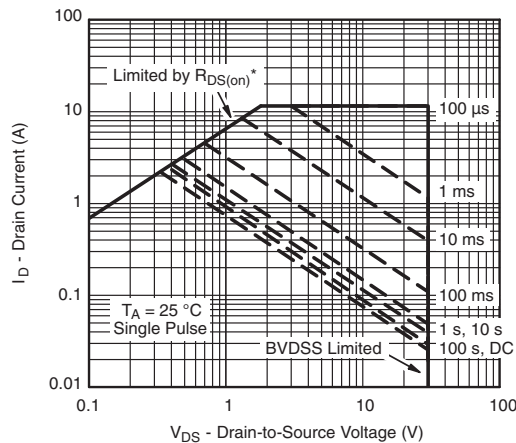
**On-Resistance vs. Gate-to-Source Voltage**



**Threshold Voltage**



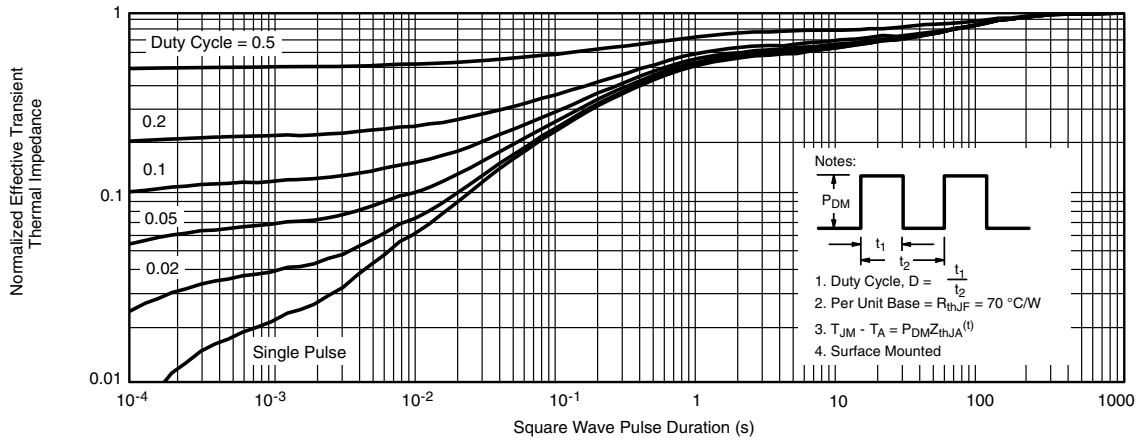
**Single Pulse Power, Junction-to-Ambient**



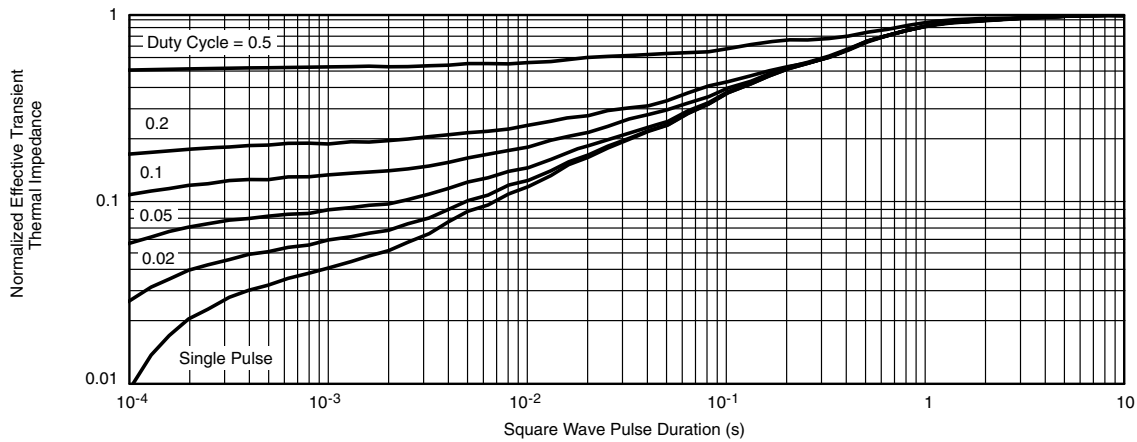
**Safe Operating Area, Junction-to-Ambient**



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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## SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A <sub>1</sub>	0.01	0.10	0.0004	0.004
A <sub>2</sub>	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E <sub>1</sub>	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e <sub>1</sub>	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L <sub>1</sub>	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01  
 DWG: 5479

## RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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